



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: ITOH, Akio

Serial No.: 09/594,091

Filed: June 15, 2000

Group Art Unit: 2815

Examiner: Matthew Warren

P.T.O. Confirmation No.: 8583

#14/B
Amend
J. McNeill
12/4/02

For. SEMICONDUCTOR MEMORY DEVICE HAVING PLANARIZED UPPER SURFACE AND A SiON MOISTURE BARRIER (as amended)

RESPONSE UNDER 37 CFR §1.116
- EXPEDITED RESPONSE -
GROUP ART UNIT 2815

BOX AF

Commissioner for Patents
Washington, D.C. 20231

November 27, 2002

Entered
J. McNeill
1/10/03

Sir:

In response to the Office Action dated July 31, 2002, please amend the above-identified application as follows:

IN THE TITLE:

Please amend the title of the invention, in its entirety, so as to read as follows:

-- SEMICONDUCTOR MEMORY DEVICE HAVING PLANARIZED UPPER SURFACE AND A SiON MOISTURE BARRIER --.

IN THE CLAIMS:

Please amend claims 1, 5 and 12 as indicated below:

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SUB C1
B1

1. (Twice Amended) A semiconductor device, comprising:
a contact;